

# WP934MD/LILGD

T-1 (3mm) Bi-Level Circuit Board Indicator



# **DESCRIPTIONS**

- The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode
- The Green source color devices are made with Gallium Phosphide Green Light Emitting Diode

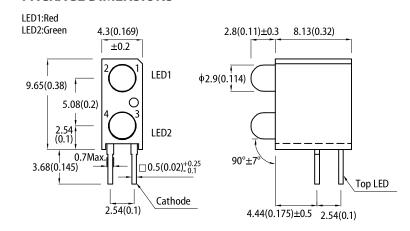
## **FEATURES**

- · Pre-trimmed leads for pc mounting
- · Black case enhances contrast ratio
- · High reliability life measured in years
- Housing UL rating: 94V-0
- Housing material: Type 66 nylon
- RoHS compliant

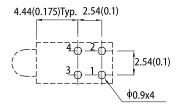
### **APPLICATIONS**

- · Status indicator
- Illuminator
- Signage applications
- · Decorative and entertainment lighting
- · Commercial and residential architectural lighting

## **PACKAGE DIMENSIONS**



Recommended PCB Layout



- All dimensions are in millimeters (inches).
   Tolerance is ±0.25(0.01") unless otherwise noted.
- Lead spacing is measured where the leads emerge from the package.
   The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice

# **SELECTION GUIDE**

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 2mA [2]		Viewing Angle [1]
			Min.	Тур.	201/2
WP934MD/LILGD	High Efficiency Red (GaAsP/GaP)		0.8	2	50°
		Red Diffused	*0.5	*1.2	
	☐ Green (GaP)	Green Diffused	1	3	- 50°
			*1	*3	

Notes.

1. 61/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

2. Luminous intensity / luminous flux: +/-15%.

\* Luminous intensity value is traceable to CIE127-2007 standards.





# ELECTRICAL / OPTICAL CHARACTERISTICS at T<sub>A</sub>=25°C

Parameter	Comple of	Fusition Calan	Value		l l m i 4
Parameter	Symbol	Emitting Color	Тур.	Max.	Unit
Wavelength at Peak Emission I <sub>F</sub> = 2mA	$\lambda_{peak}$	High Efficiency Red Green	627 565	-	nm
Dominant Wavelength I <sub>F</sub> = 2mA	λ <sub>dom</sub> <sup>[1]</sup>	High Efficiency Red Green	617 568	-	nm
Spectral Bandwidth at 50% Φ REL MAX I <sub>F</sub> = 2mA	Δλ	High Efficiency Red Green	45 30	-	nm
Capacitance	С	High Efficiency Red Green	15 15	-	pF
Forward Voltage I <sub>F</sub> = 2mA	V <sub>F</sub> <sup>[2]</sup>	High Efficiency Red Green	1.7 1.9	2.1 2.25	V
Reverse Current (V <sub>R</sub> = 5V)	I <sub>R</sub>	High Efficiency Red Green	-	10 10	μΑ
Temperature Coefficient of $\lambda_{peak}$ I <sub>F</sub> = 2mA, -10° C $\leq$ T $\leq$ 85° C	$TC_{\lambda peak}$	High Efficiency Red Green	0.13 0.1	-	nm/°C
Temperature Coefficient of $\lambda_{dom}$ I <sub>F</sub> = 2mA, -10° C $\leq$ T $\leq$ 85° C	TC <sub>λdom</sub>	High Efficiency Red Green	0.06 0.06	-	nm/°C
Temperature Coefficient of $V_F$ I <sub>F</sub> = 2mA, -10°C $\leq$ T $\leq$ 85°C	TC <sub>V</sub>	High Efficiency Red Green	-1.9 -2	-	mV/°C

# ABSOLUTE MAXIMUM RATINGS at T<sub>A</sub>=25°C

	Symbol	Valu			
Parameter		High Efficiency Red	Green	Unit	
Power Dissipation	P <sub>D</sub>	75	62.5	mW	
Reverse Voltage	$V_R$	5	5	V	
Junction Temperature	T <sub>j</sub>	125	110	°C	
Operating Temperature	T <sub>op</sub>	-40 to +85		°C	
Storage Temperature	T <sub>stg</sub>	-40 to +85		°C	
DC Forward Current	I <sub>F</sub>	30	25	mA	
Peak Forward Current	I <sub>FM</sub> <sup>[1]</sup>	160	140	mA	
Electrostatic Discharge Threshold (HBM)	-	8000	8000	V	
Thermal Resistance (Junction / Ambient)	R <sub>th JA</sub> [2]	680	680	°C/W	
Thermal Resistance (Junction / Solder point)	R <sub>th JS</sub> [2]	450	460	°C/W	
Lead Solder Temperature [3]		260°C For 3 Seconds			
Lead Solder Temperature [4]		260°C For 5 Seconds			

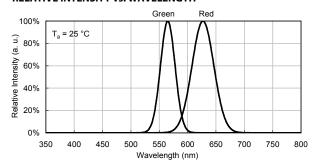
The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd:±1nm.)
 Forward voltage: ±0.1V.
 Wavelength value is traceable to CIE127-2007 standards.
 Excess driving current and /or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

Notes:
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. R<sub>in JA</sub>, R<sub>in JS</sub> Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).
3. 2mm below package base.
4. 5mm below package base.
5. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

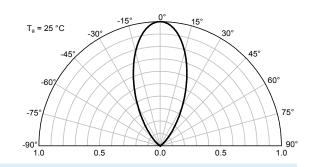


### **TECHNICAL DATA**

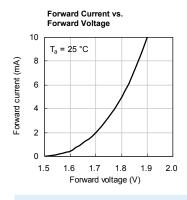
### **RELATIVE INTENSITY vs. WAVELENGTH**

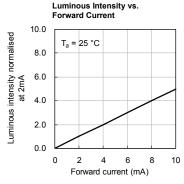


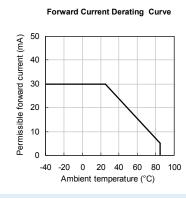
# **SPATIAL DISTRIBUTION**

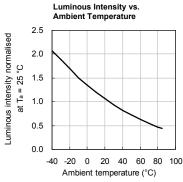


# **HIGH EFFICIENCY RED**

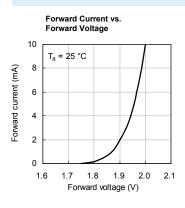


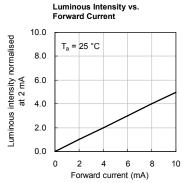


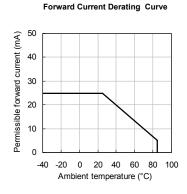


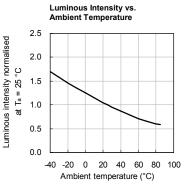


# **GREEN**

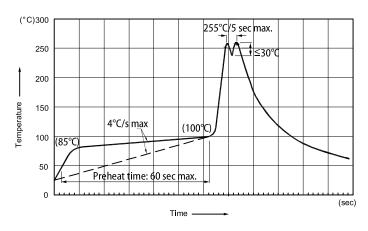








## **RECOMMENDED WAVE SOLDERING PROFILE**



- 1. Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C
- 2. Peak wave soldering temperature between 245°C ~ 255°C for 3 sec (5 sec max).

  3. Do not apply stress to the epoxy resin while the temperature is above 85°C.

  4. Fixtures should not incur stress on the component when mounting and during soldering process.

- 5. SAC 305 solder alloy is recommended.6. No more than one wave soldering pass